## Thermal Excitation of Carriers

We want to calculate the number of charge carriers at a temperature T in a simple semiconductor. The probability that a state at energy  $\varepsilon$  is occupied is

$$f(\varepsilon) = \frac{1}{e^{(\varepsilon - \mu)/k_B T}}$$
.

The value of  $\mu$  is fixed to give the correct number of particles in the system. We will also need the density of states for the conduction and valence band:

$$conduction \ band \qquad g(\varepsilon) = \frac{V}{2\pi^2\hbar^3} \left(2m_e\right)^{3/2} \sqrt{\varepsilon - E_G}$$

and

$$\mbox{valence band} \qquad g(\varepsilon) = \frac{V}{2\pi^2\hbar^3} \left(2m_h\right)^{3/2} \sqrt{-\varepsilon} \,. \label{eq:general}$$

Sketch the density of states and the Fermi function as function of energy on a single plot.

If  $\varepsilon - \mu \gg k_B T$  find an approximation for  $f(\varepsilon)$ . Use this to calculate the number of electrons in the conduction band

$$n = \frac{1}{V} \int_{E_G}^{\infty} f(\varepsilon) g(\varepsilon) d\varepsilon ,$$

and write the answer in terms of  $N_C = 2(2\pi m_e k_B T/h^2)^{3/2}$ . Next calculate the number of holes in the valence band

$$p = \frac{1}{V} \int_{-\infty}^{0} [1 - f(\varepsilon)] g(\varepsilon) d\varepsilon,$$

and write the answer in terms of  $N_V = 2(2\pi m_h k_B T/h^2)^{3/2}$ .

Show that np is independent of the value of the chemical potential  $\mu$ .